8-stage shift-and-store register Rev. 12 — 25 March 2016

Product data sheet

#### 1. **General description**

The HEF4094B is an 8-stage serial shift register. It has a storage latch associated with each stage for strobing data from the serial input to parallel buffered 3-state outputs QP0 to QP7. The parallel outputs may be connected directly to common bus lines. Data is shifted on positive-going clock transitions. The data in each shift register stage is transferred to the storage register when the strobe (STR) input is HIGH. Data in the storage register appears at the outputs whenever the output enable (OE) signal is HIGH.

Two serial outputs (QS1 and QS2) are available for cascading a number of HEF4094B devices. Serial data is available at QS1 on positive-going clock edges to allow high-speed operation in cascaded systems with a fast clock rise time. The same serial data is available at QS2 on the next negative going clock edge. This is used for cascading HEF4094B devices when the clock has a slow rise time.

It operates over a recommended V<sub>DD</sub> power supply range of 3 V to 15 V referenced to V<sub>SS</sub> (usually ground). Unused inputs must be connected to V<sub>DD</sub>, V<sub>SS</sub>, or another input.

#### **Features and benefits** 2.

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C and -40 °C to +125 °C
- Complies with JEDEC standard JESD 13-B

#### 3. Ordering information

#### Table 1. **Ordering information**

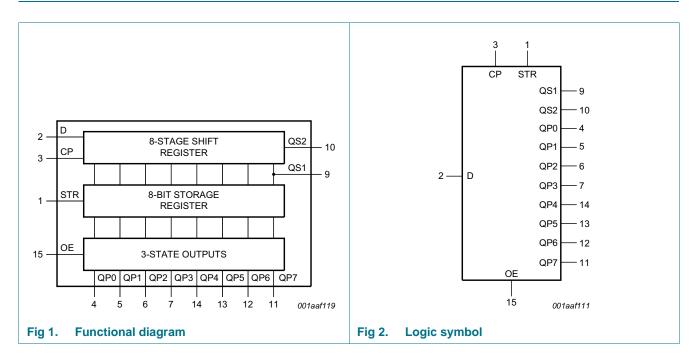
All types operate from  $-40 \degree$ C to  $+125 \degree$ C.

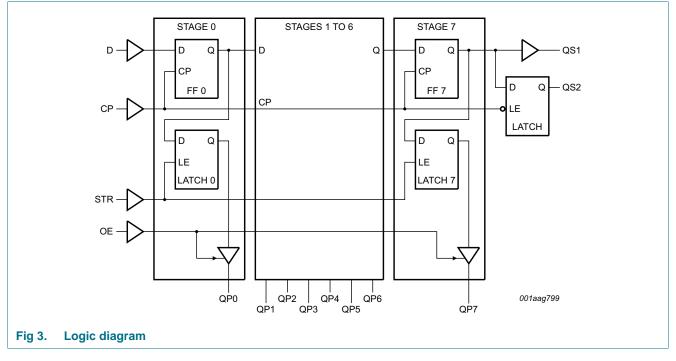
Type number	Package	Package								
	Name	Description	Version							
HEF4094BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1							
HEF4094BTS	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1							
HEF4094BTT	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1							



8-stage shift-and-store register

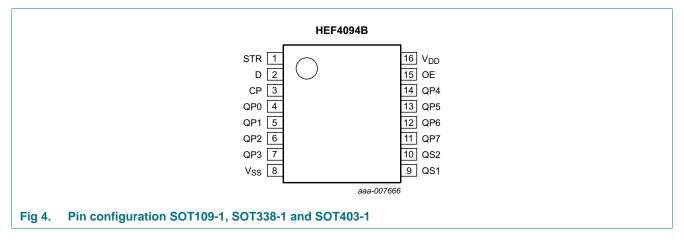
### 4. Functional diagram





## 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

Table 2.	Pin description

Symbol	Pin	Description
STR	1	strobe input
D	2	data input
СР	3	clock input
QP0 to QP7	4, 5, 6, 7, 14, 13, 12, 11	parallel output
V <sub>SS</sub>	8	ground supply voltage
QS1	9	serial output
QS2	10	serial output
OE	15	output enable input
V <sub>DD</sub>	16	supply voltage

### 6. Functional description

#### Table 3. Function table<sup>[1]</sup>

Inputs					outputs	Serial out	Serial outputs	
СР	OE	STR	D	QP0	QPn	QS1	QS2	
1	L	X	Х	Z	Z	Q6S	NC	
$\downarrow$	L	X	Х	Z	Z	NC	Q7S	
↑	Н	L	Х	NC	NC	Q6S	NC	
↑	Н	Н	L	L	QPn –1	Q6S	NC	
1	Н	Н	Н	Н	QPn –1	Q6S	NC	
$\downarrow$	Н	Н	Н	NC	NC	NC	Q7S	

[1] At the positive clock edge, the information in the 7th register stage is transferred to the 8th register stage and the QSn outputs.

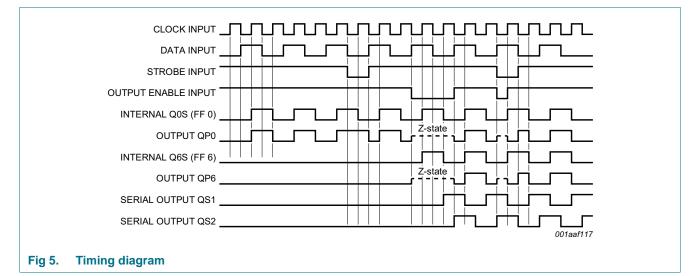
H = HIGH voltage level; L = LOW voltage level; X = don't care;

 $\uparrow$  = positive-going transition;  $\downarrow$  = negative-going transition;

Z = HIGH-impedance OFF-state; NC = no change;

Q6S = the data in register stage 6 before the LOW to HIGH clock transition;

Q7S = the data in register stage 7 before the HIGH to LOW clock transition.



### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V<sub>SS</sub> = 0 V (ground).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DD</sub>	supply voltage			-0.5	+18	V
I <sub>IK</sub>	input clamping current	$V_{I}$ < -0.5 V or $V_{I}$ > $V_{DD}$ + 0.5 V		-	±10	mA
VI	input voltage			-0.5	V <sub>DD</sub> + 0.5	V
l <sub>ок</sub>	output clamping current	$V_{O}$ < -0.5 V or $V_{O}$ > $V_{DD}$ + 0.5 V		-	±10	mA
I <sub>I/O</sub>	input/output current			-	±10	mA
I <sub>DD</sub>	supply current			-	50	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
T <sub>amb</sub>	ambient temperature			-40	+125	°C
P <sub>tot</sub>	total power dissipation	SO16, SSOP16 and TSSOP16	[1]	-	500	mW
Р	power dissipation	per output		-	100	mW

[1] For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

For (T)SSOP16 package: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.

### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DD</sub>	supply voltage		3	-	15	V
VI	input voltage		0	-	V <sub>DD</sub>	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V <sub>DD</sub> = 5 V	-	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	-	0.08	μs/V

#### **Static characteristics** 9.

#### **Static characteristics** Table 6.

 $V_{SS} = 0$  V;  $V_{I} = V_{SS}$  or  $V_{DD}$ ; unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>DD</sub>	T <sub>amb</sub> =	–40 °C	T <sub>amb</sub> =	+25 °C	T <sub>amb</sub> =	+85 °C	T <sub>amb</sub> = +125 °C		Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
VIH	HIGH-level	I <sub>0</sub>   < 1 μA	5 V	3.5	-	3.5	-	3.5	-	3.5	-	V
	input voltage		10 V	7.0	-	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	11.0	-	V
V <sub>IL</sub>	LOW-level	$ I_0  < 1 \ \mu A$	5 V	-	1.5	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V	-	3.0	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	-	4.0	V
V <sub>OH</sub>	HIGH-level	I <sub>0</sub>   < 1 μA	5 V	4.95	-	4.95	-	4.95	-	4.95	-	V
	output voltage		10 V	9.95	-	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	14.95	-	V
V <sub>OL</sub>	LOW-level	/-level  I <sub>O</sub>   < 1 μA	5 V	-	0.05	-	0.05	-	0.05	-	0.05	V
output voltage	output voltage		10 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	-	0.05	V
I <sub>OH</sub>	HIGH-level	V <sub>O</sub> = 2.5 V	5 V	-	-1.7	-	-1.4	-	-1.1	-	-1.1	mA
	output current	V <sub>O</sub> = 4.6 V	5 V	-	-0.64	-	-0.5	-	-0.36	-	-0.36	mA
		V <sub>O</sub> = 9.5 V	10 V	-	-1.6	-	-1.3	-	-0.9	-	-0.9	mA
		V <sub>O</sub> = 13.5 V	15 V	-	-4.2	-	-3.4	-	-2.4	-	-2.4	mA
I <sub>OL</sub>	LOW-level	V <sub>O</sub> = 0.4 V	5 V	0.64	-	0.5	-	0.36	-	0.36	-	mA
	output current	V <sub>O</sub> = 0.5 V	10 V	1.6	-	1.3	-	0.9	-	0.9	-	mA
		V <sub>O</sub> = 1.5 V	15 V	4.2	-	3.4	-	2.4	-	2.4	-	mA
I <sub>OZ</sub>	OFF-state output current	QPn output is HIGH; V <sub>O</sub> = 15 V	15 V	-	0.4	-	0.4	-	12	-	12	μA
l <sub>l</sub>	input leakage current		15 V	-	±0.1	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>DD</sub>	supply current	all valid input	5 V	-	5	-	5	-	150	-	150	μA
		combinations;	10 V	-	10	-	10	-	300	-	300	μA
		I <sub>O</sub> = 0 A	15 V	-	20	-	20	-	600	-	600	μA
CI	input capacitance			-	-	-	7.5	-	-	-	-	pF

### **10.** Dynamic characteristics

#### Table 7. Dynamic characteristics

 $V_{SS} = 0 V$ ;  $T_{amb} = 25$ °C; for test circuit see <u>Figure 10</u>; unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>DD</sub>	Extrapolation formula	Min	Тур	Max	Unit
t <sub>PHL</sub>	HIGH to LOW	CP to QS1;	5 V [1]	108 ns + (0.55 ns/pF)C <sub>L</sub>	-	135	270	ns
	propagation delay	see <u>Figure 6</u>	10 V	54 ns + (0.23 ns/pF)C <sub>L</sub>	-	65	130	ns
			15 V	42 ns + (0.16 ns/pF)C <sub>L</sub>	-	50	100	ns
		CP to QS2;	5 V	78 ns + (0.55 ns/pF)C <sub>L</sub>	-	105	210	ns
		see <u>Figure 6</u>	10 V	39 ns + (0.23 ns/pF)C <sub>L</sub>	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF)C <sub>L</sub>	-	40	80	ns
	CP to QPn;	5 V	138 ns + (0.55 ns/pF)C <sub>L</sub>	-	165	330	ns	
		see <u>Figure 6</u>	10 V	64 ns + (0.23 ns/pF)C <sub>L</sub>	-	75	150	ns
			15 V	47 ns + (0.16 ns/pF)C <sub>L</sub>	-	55	110	ns
		STR to QPn;	5 V	83 ns + (0.55 ns/pF)C <sub>L</sub>	-	110	220	ns
		see Figure 7	10 V	39 ns + (0.23 ns/pF)C <sub>L</sub>	-	50	100	ns
			15 V	27 ns + (0.16 ns/pF)C <sub>L</sub>	-	35	70	ns
t <sub>PLH</sub>	LOW to HIGH	CP to QS1;	5 V [1]	78 ns + (0.55 ns/pF)C <sub>L</sub>	-	105	210	ns
	propagation delay,	see <u>Figure 6</u>	10 V	39 ns + (0.23 ns/pF)C <sub>L</sub>	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF)C <sub>L</sub>	-	40	80	ns
		CP to QS2;	5 V	78 ns + (0.55 ns/pF)C <sub>L</sub>	-	105	210	ns
		see Figure 6	10 V	39 ns + (0.23 ns/pF)C <sub>L</sub>	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF)C <sub>L</sub>	-	40	80	ns
		CP to QPn;	5 V	123 ns + (0.55 ns/pF)C <sub>L</sub>	-	150	300	ns
		see <u>Figure 6</u>	10 V	59 ns + (0.23 ns/pF)C <sub>L</sub>	-	70	140	ns
			15 V	47 ns + (0.16 ns/pF)C <sub>L</sub>	-	55	110	ns
		STR to QPn; see <u>Figure 7</u>	5 V	73 ns + (0.55 ns/pF)C <sub>L</sub>	-	100	200	ns
			10 V	34 ns + (0.23 ns/pF)C <sub>L</sub>	-	45	90	ns
			15 V	27 ns + (0.16 ns/pF)C <sub>L</sub>	-	35	70	ns
t <sub>t</sub>	transition time		5 V [1]	10 ns + (1.00 ns/pF)C <sub>L</sub>	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF)C <sub>L</sub>	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C <sub>L</sub>	-	20	40	ns
t <sub>PZH</sub>	OFF-state to HIGH	OE to QPn;	5 V		-	40	80	ns
	propagation delay	see Figure 8	10 V		-	25	50	ns
			15 V		-	20	40	ns
t <sub>PZL</sub>	OFF-state to LOW	OE to QPn;	5 V		-	40	80	ns
	propagation delay	see Figure 8	10 V		-	25	50	ns
			15 V		-	20	40	ns
t <sub>PHZ</sub>	HIGH to OFF-state	OE to QPn;	5 V		-	75	150	ns
	propagation delay	see <u>Figure 8</u>	10 V		-	40	80	ns
			15 V		-	30	60	ns

8-stage shift-and-store register

Symbol	Parameter	Conditions	V <sub>DD</sub>	Extrapolation formula	Min	Тур	Max	Unit
PLZ	LOW to OFF-state	OE to QPn;	5 V		-	80	160	ns
	propagation delay	see <u>Figure 8</u>	10 V		-	40	80	ns
		15 V		-	30	60	ns	
su	set-up time	D to CP;	5 V		60	30	-	ns
	see Figure 9	10 V		20	10	-	ns	
		15 V		15	5	-	ns	
t <sub>h</sub> hold time	D to CP; see <u>Figure 9</u>	5 V		+5	-15	-	ns	
		10 V		20	5	-	ns	
			15 V		20	5	-	ns
w	pulse width	minimum LOW clock pulse;	5 V		60	30	-	ns
			10 V		30	15	-	ns
		see <u>Figure 6</u>	15 V		24	12	-	ns
		minimum HIGH	5 V		40	20	-	ns
		strobe pulse;	10 V		30	15	-	ns
		see Figure 7	15 V		24	12	-	ns
max	maximum frequency	see Figure 6	5 V		5	10	-	MHz
			10 V		11	22	-	MHz
			15 V		14	28	-	MHz
	1	1	1				1	1

# Table 7. Dynamic characteristics ...continued Visit To an experimental structure for the transition of the transitio

ified

[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C<sub>L</sub> in pF).

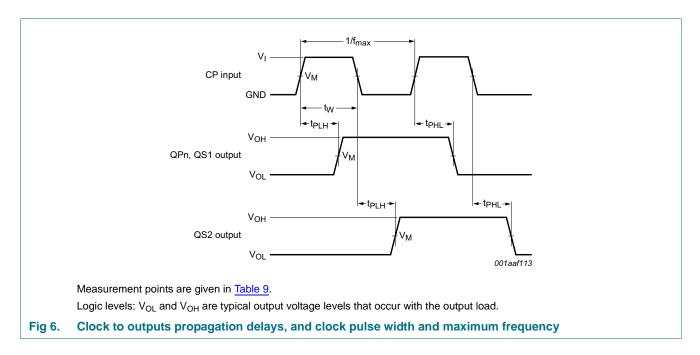
#### Table 8. Dynamic power dissipation

 $V_{SS} = 0 V; t_r = t_f \le 20 ns; T_{amb} = 25$ °C.

Symbol	Parameter	V <sub>DD</sub>	Typical formula for $P_D$ ( $\mu$ W)	where:
P <sub>D</sub>	dynamic power	5 V	$P_D = 2100 \times f_i + \Sigma(f_o \times C_L) \times V_DD{}^2$	$f_i = input frequency in MHz,$
dissipation		10 V	$P_D = 9700 \times f_i + \Sigma(f_o \times C_L) \times V_DD^2$	$f_o = output frequency in MHz,$
		15 V	$P_{D} = 26000 \times f_{i} + \Sigma(f_{o} \times C_{L}) \times V_{DD}^{2}$	$C_L$ = output load capacitance in pF,
				$V_{DD}$ = supply voltage in V,
				$\Sigma(f_o \times C_L)$ = sum of the outputs.

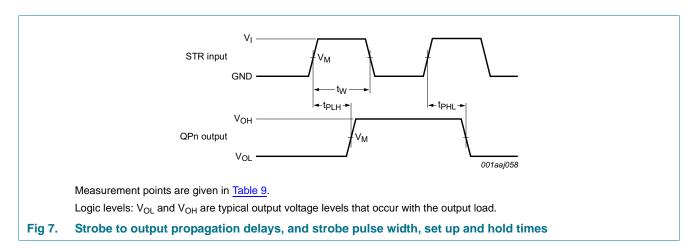
8-stage shift-and-store register

### 11. Waveforms



#### Table 9. Measurement points

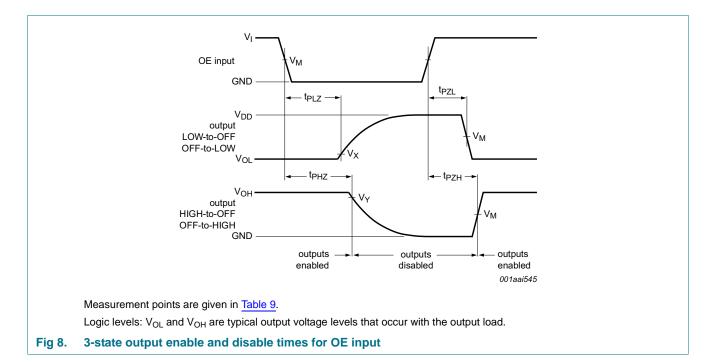
Supply voltage	Input	Output				
V <sub>DD</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>		
5 V to 15 V	0.5V <sub>DD</sub>	0.5V <sub>DD</sub>	0.1V <sub>DD</sub>	0.9V <sub>DD</sub>		

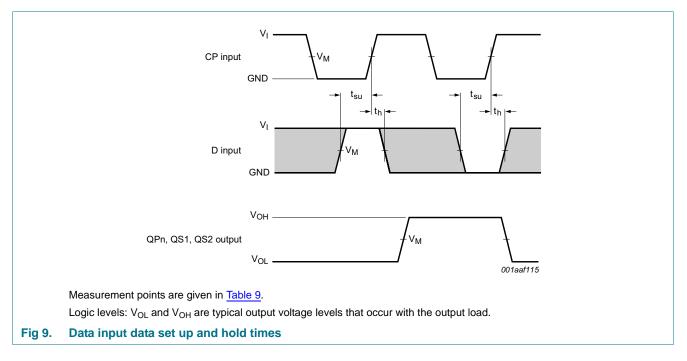


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# **HEF4094B**

#### 8-stage shift-and-store register



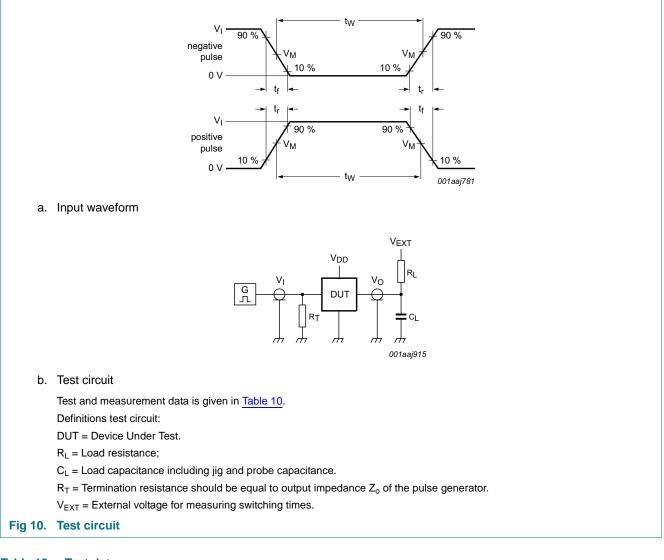


10 of 19

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# HEF4094B

#### 8-stage shift-and-store register



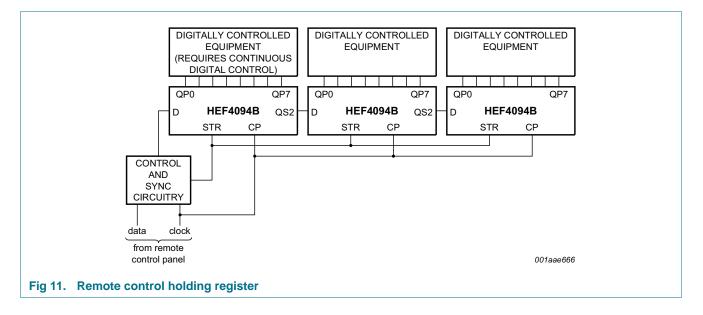
#### Table 10. Test data

Supply voltage	Input		V <sub>EXT</sub>			Load	
V <sub>DD</sub>	VI tr, tf		t <sub>PHL</sub> , t <sub>PLH</sub>	PHL, tPLH tPHZ, tPZH tPLZ		C <sub>L</sub> R <sub>L</sub>	
5 V to 15 V	$V_{\text{SS}} \text{ or } V_{\text{DD}}$	≤ 20 ns	open	V <sub>SS</sub>	V <sub>DD</sub>	50 pF	1 kΩ

### **12.** Application information

Some examples of applications for the HEF4094B are:

- Serial-to-parallel data conversion
- Remote control holding register

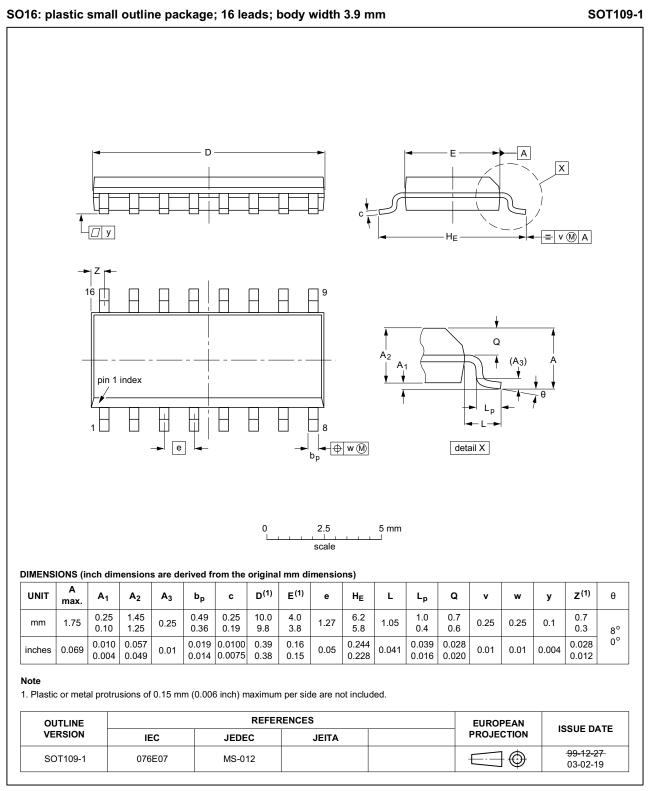


HEF4094B

12 of 19

8-stage shift-and-store register

### 13. Package outline



#### Fig 12. Package outline SOT109-1 (SO16)

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8-stage shift-and-store register

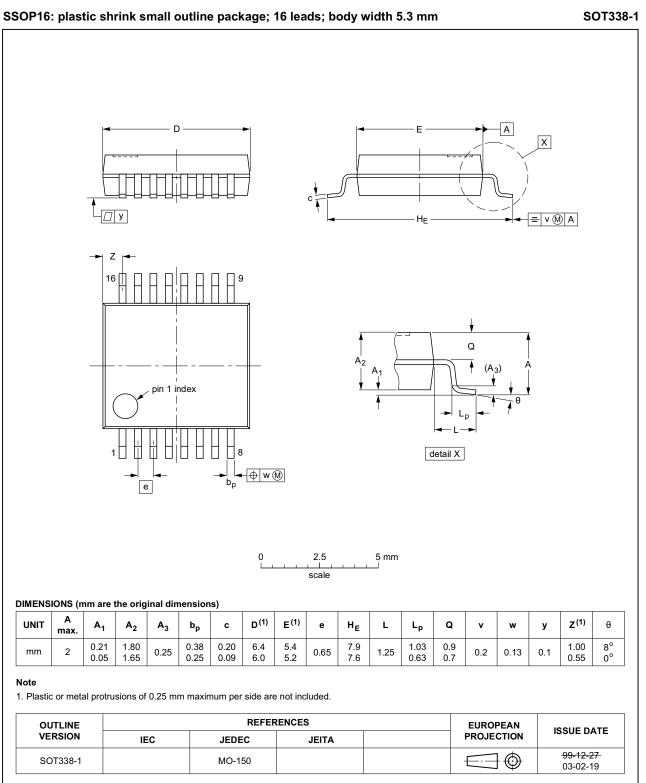


Fig 13. Package outline SOT338-1 (SSOP16)

8-stage shift-and-store register

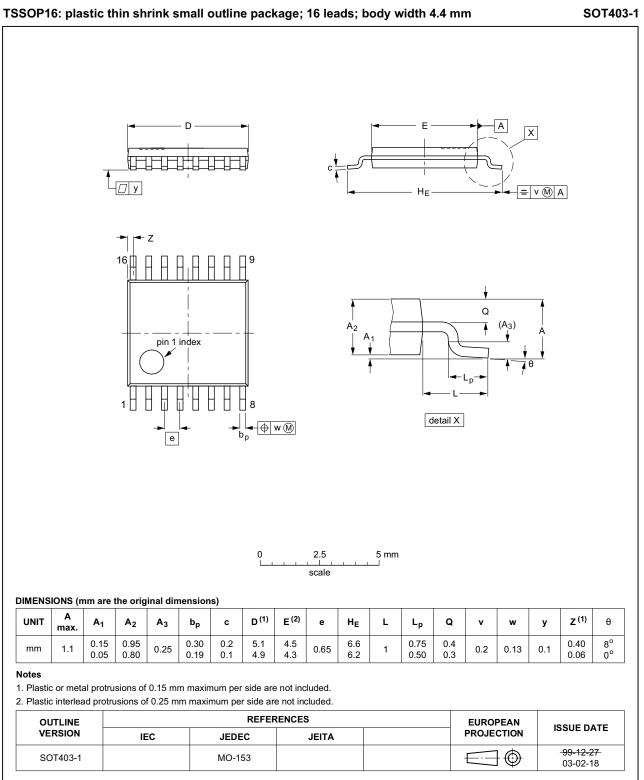


Fig 14. Package outline SOT403-1 (TSSOP16)

8-stage shift-and-store register

### 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4094B v.12	20160325	Product data sheet	-	HEF4094B v.11
Modifications:	Type number HEF4094BP (SOT38-4) removed.			
HEF4094B v.11	20130829	Product data sheet	-	HEF4094B v.10
Modifications:	• <u>Table 4</u> : Table note corrected (errata).			
HEF4094B v.10	20130625	Product data sheet	-	HEF4094B v.9
Modifications:	added type number HEF4094BTT.			
HEF4094B v.9	20111116	Product data sheet	-	HEF4094B v.8
Modifications:	<u>Table 6</u> : I <sub>OH</sub> minimum values changed to maximum			
HEF4094B v.8	20100402	Product data sheet	-	HEF4094B v.7
HEF4094B v.7	20091216	Product data sheet	-	HEF4094B v.6
HEF4094B v.6	20091103	Product data sheet	-	HEF4094B v.5
HEF4094B v.5	20090728	Product data sheet	-	HEF4094B v.4
HEF4094B v.4	20081030	Product data sheet	-	HEF4094B_CNV v.3
HEF4094B_CNV v.3	19950101	Product specification	-	HEF4094B_CNV v.2
HEF4094B_CNV v.2	19950101	Product specification	-	-

### 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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### **17. Contents**

1	General description 1
2	Features and benefits 1
3	Ordering information 1
4	Functional diagram 2
5	Pinning information 3
5.1	Pinning
5.2	Pin description 3
6	Functional description 4
7	Limiting values 5
8	Recommended operating conditions 5
9	Static characteristics 6
10	Dynamic characteristics 7
11	Waveforms 9
12	Application information 12
13	Package outline 13
14	Revision history 16
15	Legal information 17
15.1	Data sheet status 17
15.2	Definitions 17
15.3	Disclaimers
15.4	Trademarks 18
16	Contact information 18
17	Contents 19

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